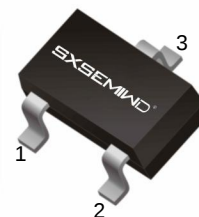


FEATURES

High current surface mount PNP silicon switching transistor for
Load management in portable applications

SOT-23



1. BASE
2. EMITTER
3. COLLECTOR

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CB0}	Collector-Base Voltage	-50	V
V _{CEO}	Collector-Emitter Voltage	-30	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current -Continuous	-1	A
P _C	Collector Power Dissipation	310	mW
R _{θJA}	Thermal Resistance, junction to Ambient	403	°C/W
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55-150	°C

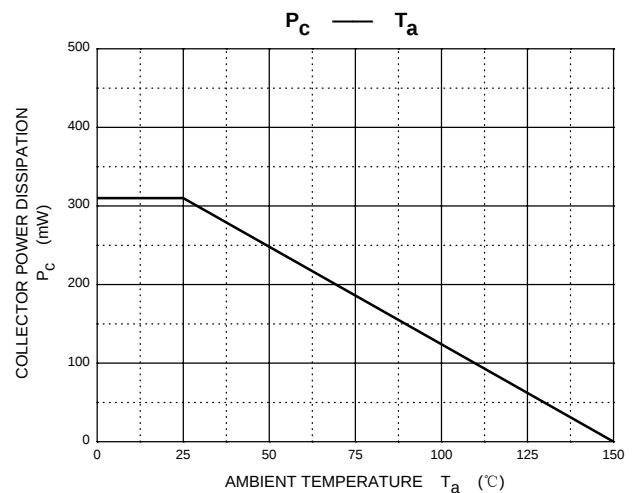
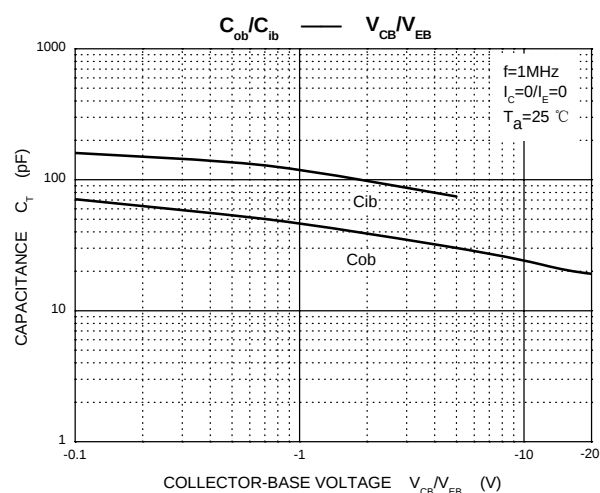
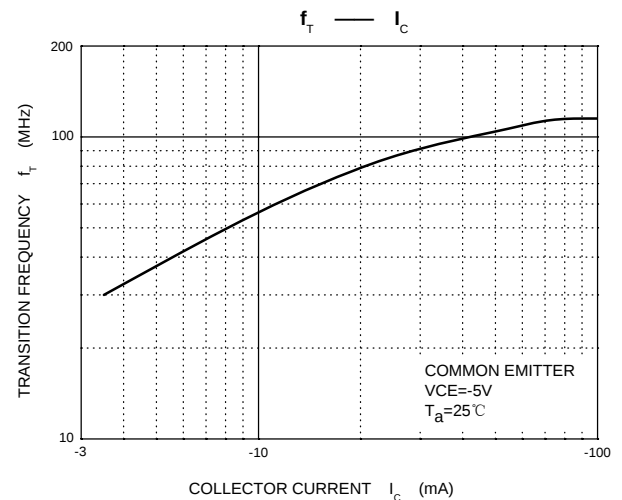
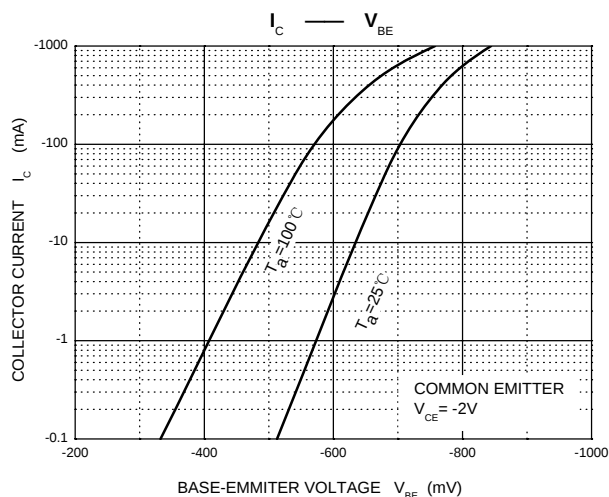
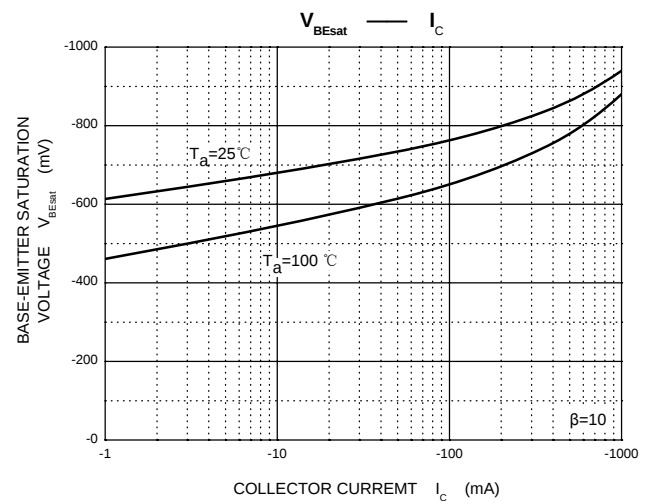
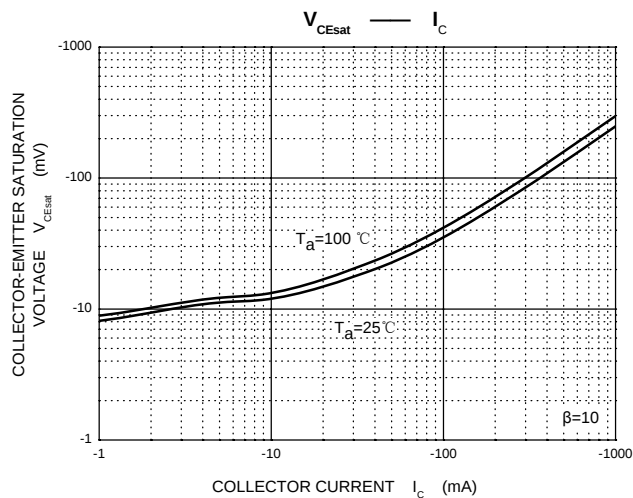
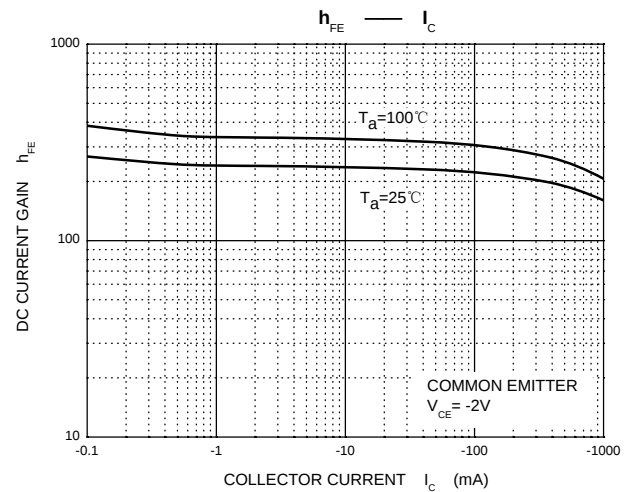
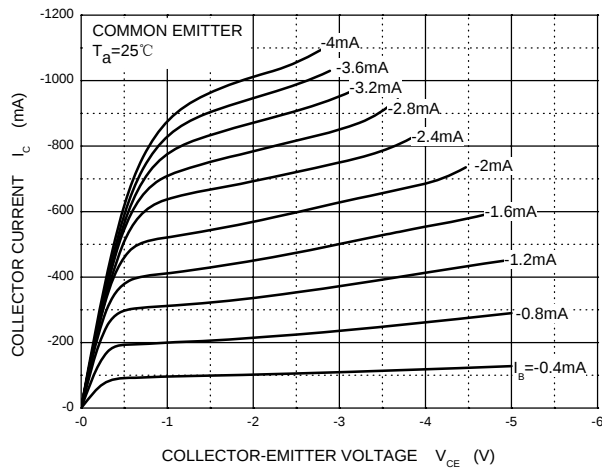
MARKING :589

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

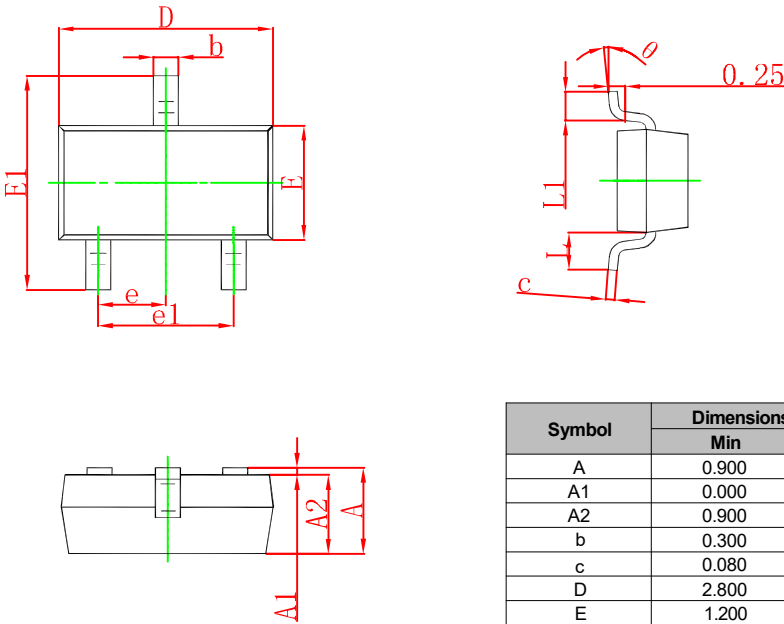
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-100μA, I _E =0	-50			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-10mA, I _B =0	-30			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-100μA, I _C =0	-5			V
Collector cut-off current	I _{CBO}	V _{CB} =-30V, I _E =0			-0.1	μA
Collector-emitter cut-off current	I _{CES}	V _{CE} =-30V			-0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =-4V, I _C =0			-0.1	μA
DC current gain	h _{FE1}	V _{CE} =-2V, I _C =-1mA	100			
	h _{FE2}	V _{CE} =-2V, I _C =-500mA	100		300	
	h _{FE3}	V _{CE} =-2V, I _C =-1A	80			
	h _{FE4}	V _{CE} =-2V, I _C =-2A	40			
Collector-emitter saturation voltage	V _{CE(sat)1}	I _C = -500mA, I _B =-50mA			-0.25	V
	V _{CE(sat)2}	I _C = -1A, I _B =-100mA			-0.3	V
	V _{CE(sat)3}	I _C = -2A, I _B =-200mA			-0.65	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C = -1A, I _B =-100mA			-1.2	V
Base-emitter Turn-on voltage	V _{BE(on)}	V _{CE} =-2V, I _C =-1A			-1.1	V
Transition frequency	f _T	V _{CE} =-5V, I _C =-100mA , f = 100MHz	100			MHz
Collector Output Capacitance	C _{ob}	f=1MHz			15	pF

Typical Characteristics

Static Characteristic

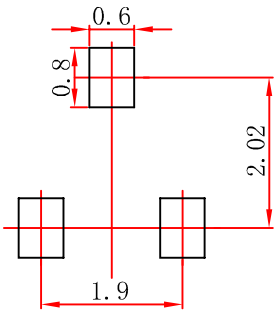


SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:
1. Controlling dimension in millimeters.
2. General tolerance: ± 0.05mm.
3. The pad layout is for reference purposes only.